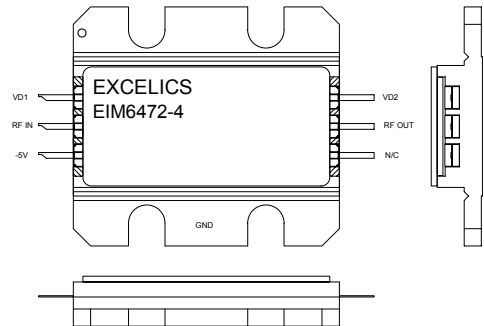


FEATURES

- 6.4-7.2GHz Operating Frequency Range
- 35.5dBm Output Power @ 1dB Compression
- 28.0 dB Typical Power Gain @1dB gain compression
- -45dBc Typical OIM3@ each tone Pout 22.5dBm
- Non-Hermetic Metal Flange Package

APPLICATIONS

- Point-to-point and point-to-multipoint radio
- Military Radar Systems



Caution! ESD sensitive device.

ELECTRICAL CHARACTERISTICS (T_b = 25 °C, 50 ohm, VD1=7V, VD2=10V, V_{gg}=-5V)

SYMBOL	PARAMETER/TEST CONDITIONS	MIN	TYP	MAX	UNITS
F	Operating Frequency Range	6.4		7.2	GHz
P1dB	Output Power @1dB Gain Compression	34.5	35.5		dBm
G1dB	Gain @1dB gain compression	24	28		dB
ΔGain	Gain Flatness		±1.5		dB
OIMD3	Output 3 rd Order Intermodulation Distortion @Δf=10MHz, Each Tone Pout 22.5dBm	-42	-45		dBc
Input RL	Input Return Loss		-12	-8	dB
Output RL	Output Return Loss		-15	-10	dB
VD1	Drain Supply Voltage 1		7		V
VD2	Drain Supply Voltage 2		10		V
I_{DQ1}	Quiescent Drain Current 1		800		mA
I_{DQ2}	Quiescent Drain Current 2		1100	1300	mA
V_{gg}	Gate Supply Voltage		-5		V
R_{th}	Thermal Resistance		4.2		°C/W
T_b	Operating Base Plate Temperature	- 30		+ 80	°C

Note: Turn on/off sequence is required: ---to turn on: apply -5V on both V_{gg} first, then +7V and +10V.
 ---to turn off: turn +7V and +10V off first, then turn -5V off

MAXIMUM RATINGS @25°C^{1,2}

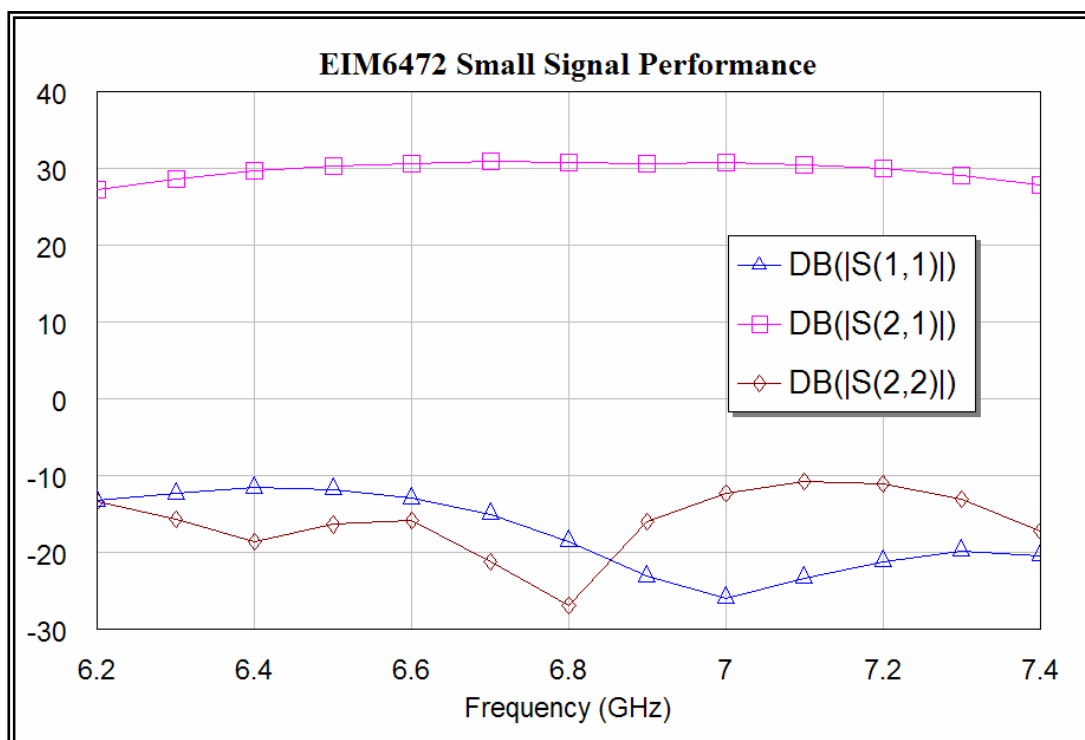
SYMBOL	CHARACTERISTIC	ABSOLUTE	CONTINUOUS ^{1,2}
V _{D1}	Drain Supply Voltage 1	12V	8V
V _{D2}	Drain Supply Voltage 2	14V	10V
V _{gg}	Gate Supply Voltage	-10V	-6 V
I _{gg}	Gate Current	150mA	50 mA
P _{IN}	Input Power	20dBm	@ 3dB compression
T _{CH}	Channel Temperature	175°C	150°C
T _{STG}	Storage Temperature	-65/175°C	-65/150°C
P _T	Total Power Dissipation	29.8W	25W

Notes: 1. Operating the device beyond any of the above rating may reduce MTF and cause permanent damage.

2. Bias conditions must also satisfy the following equation $V_{dd} \cdot I_{dd} < (T_{CH} - T_b) / R_{TH}$

Typical Performance:

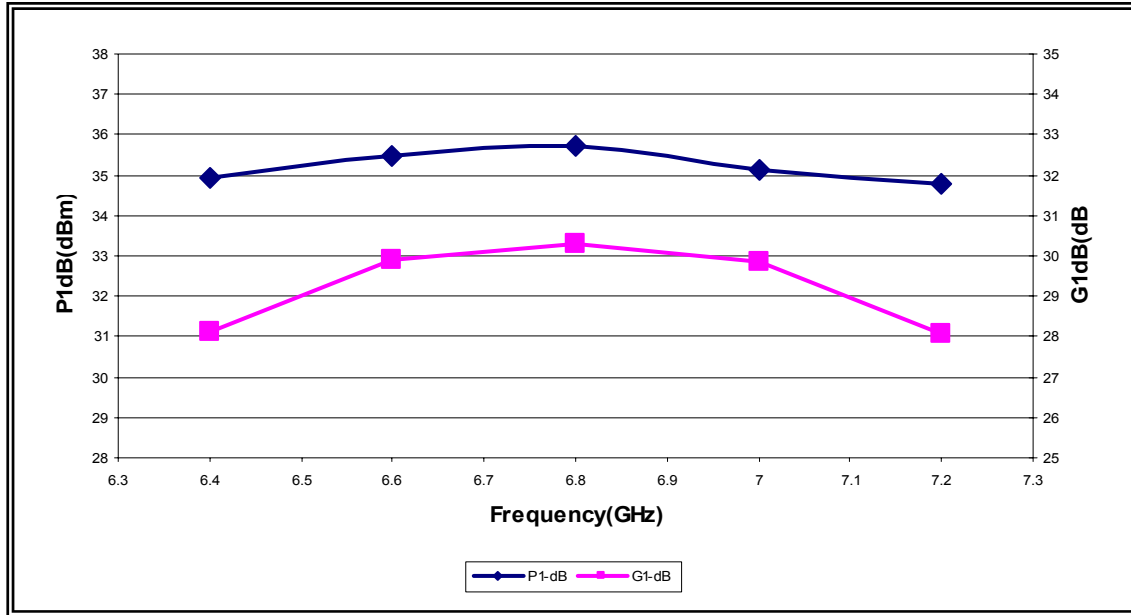
1. Small Signal Performance (@V_{d1} = 7V, V_{d2} = 10V, I_{d1} = 800mA, I_{d2} = 1100mA)



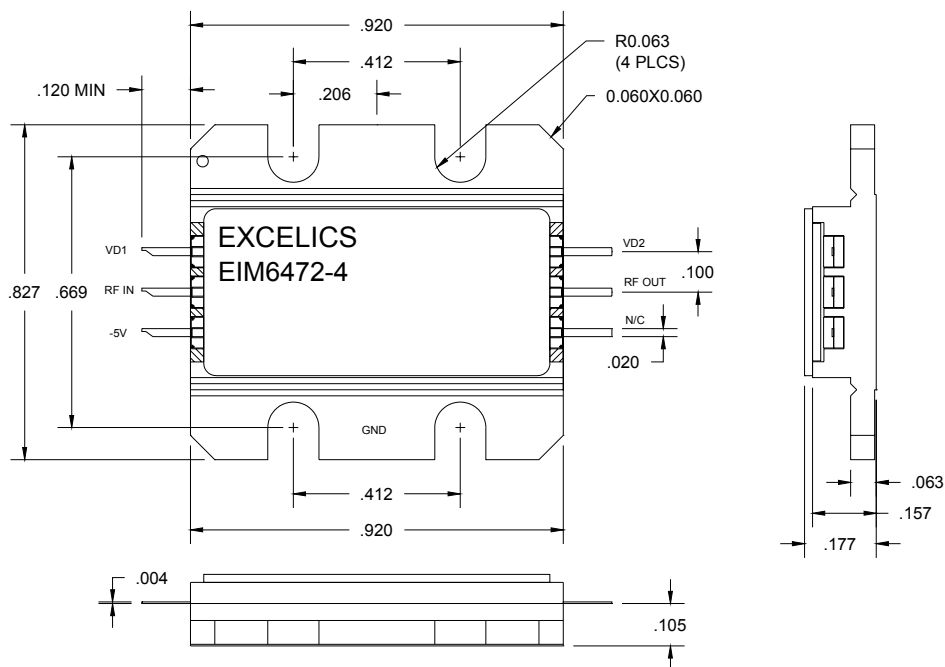
UPDATED: 01/15/2008

6.4-7.2 GHz Multi-Stage Power Amplifier

2. P1-dB & G1-dB (@V_{d1} = 7V, V_{d2} = 10V, I_{d1} = 800mA, I_{d2} = 1100mA)



Package Dimensions and Pin Assignments

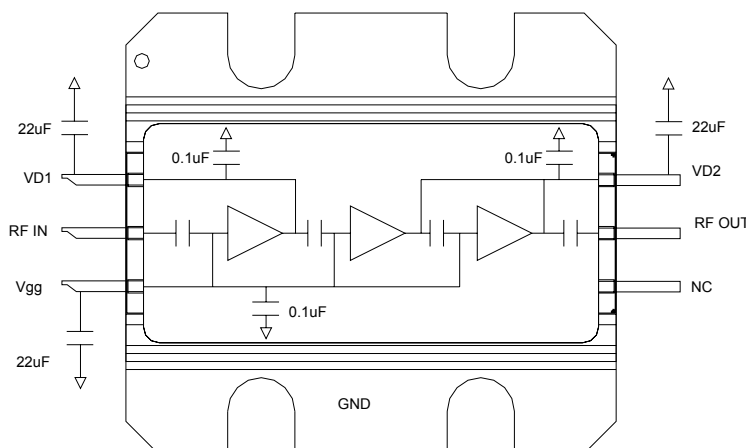


Dimensions are in inches
* NC: No connection inside the package

Specifications are subject to change without notice.

Application Note

1. The package should be screwed onto a good heat sink and ground
2. Turn on/off sequence is required:
 - to turn on: apply -5V first, then +7V and +10V.
 - to turn off: turn +7V and +10V off first, then turn -5V off
3. Recommended External Bias Circuit and Internal Block Diagram



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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.